









	<h2 style="color: #e67e22;">SUD50N03-09P-E3</h2>
	<p>Hersteller-Teilenummer: SUD50N03-09P-E3</p> <hr/> <p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p> <hr/> <p>Teil der Beschreibung: MOSFET N-CH 30V 63A TO252</p> <hr/> <p>Datenblätter:  SUD50N03-09P-E3.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 4548 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SUD50N03-09P-E3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET N-CH 30V 63A TO252
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	4548 pcs Stock
detaillierte Beschreibung	N-Channel 30V 63A (Tc) 7.5W (Ta), 65.2W (Tc)
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 175°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-252-3, DPak (2 Leads + Tab), SC-63
Supplier Device-Gehäuse	TO-252, (D-Pak)
Verlustleistung (max)	7.5W (Ta), 65.2W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	30V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	63A (Tc)
Rds On (Max) @ Id, Vgs	9.5 mOhm @ 20A, 10V
VGS (th) (Max) @ Id	3V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	16nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	2200pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	4.5V, 10V
Vgs (Max)	±20V
Verpackung	Cut Tape (CT)
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SUD50N03-09P-E3CT

SUD50N03-09P-E3 ist neu im Original, Suche SUD50N03-09P-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SUD50N03-09P-E3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SUD50N03-09P-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SUD50N03-09P-GE3 Vishay / Siliconix MOSFET N-CH 30V 63A TO252</p>	 <p>SUD50N03-10-E3 Vishay Precision Group SUD50N03-10-E3 VISHAY</p>	 <p>SUD50N03-09P-E3 Vishay / Siliconix MOSFET N-CH 30V 63A TO252</p>	 <p>SUD50N03-10 VISHAY SUD50N03-10 VISHAY</p>
 <p>SUD50N03-09P-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 30V 63A TO252</p>	 <p>SUD50N03-09 VISHAY SUD50N03-09 VISHAY</p>	 <p>SUD50N03-09P VISHAY SUD50N03-09P VISHAY</p>	 <p>SUD50N03-07AP SILICON SUD50N03-07AP SILICON</p>

heiße Teile

Mehr

⊛ SUD50N024-06P-T4-E	↔ SUD50N024-06P-T4E3	⇒ SUD50N024-09	D SUD50N024-09P	↔ SUD50N024-09P-E4E3
⊣ SUD50N024-09P-T4	⊛ SUD50N024-09P-T4E3	D SUD50N025	⇒ SUD50N025-05P	↔ SUD50N025-06P
⊛ SUD50N025-06P-E3	⊣ SUD50N025-06P-E3	⊛ SUD50N025-09	↔ SUD50N025-09BP-4E3	↔ SUD50N025-09BP-E3
D SUD50N03	⊛ SUD50N03-06	⊣ SUD50N03-06P	⊛ SUD50N03-06P-E3	↔ SUD50N03-06P-E3
⇒ SUD50N03-07	↔ SUD50N03-07AP	⊛ SUD50N03-07P	⊣ SUD50N03-09	↔ SUD50N03-09P
↔ SUD50N03-09P-E3	⇒ SUD50N03-10	D SUD50N03-10-T4	⊛ SUD50N03-10AP	⊣ SUD50N03-10BP
⊛ SUD50N03-10BP-T4	D SUD50N03-10CP	⇒ SUD50N03-10P	↔ SUD50N03-11	↔ SUD50N03-11-E3
⊣ SUD50N03-11-E3	⊛ SUD50N03-12P	↔ SUD50N03-12P-E3	⇒ SUD50N03-12P-E3	↔ SUD50N03-16P
⊛ SUD50N03-7M3P	⊣ SUD50N03A	⊛ SUD50N04-05L	D SUD50N04-05L-E3	↔ SUD50N04-05L-E3
↔ SUD50N04-06H	⊛ SUD50N04-06P	⊣ SUD50N04-07	⊛ SUD50N04-07-T4-GE3	↔ SUD50N04-07L

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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